# XBS024S15R-G



ETR1605-003

## Schottky Barrier Diode, 200mA, 40V Type

## **■**FEATURES

Forward Voltage :  $V_F$ =0.53V (TYP.)

Forward Current :  $I_{F(AV)}$ =200mA Repetitive Peak Reverse Voltage :  $V_{RM}$ =40V

Environmentally Friendly : EU RoHS Compliant, Pb Free

## **■**APPLICATIONS

●Low Current Rectification

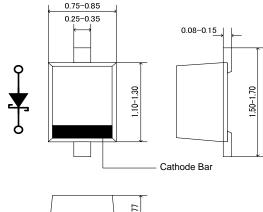
### ■ ABSOLUTE MAXIMUM RATINGS

### Ta=25°C

PARMETER	SYMBOL	RATINGS	UNIT	
Repetitive Peak Voltage	VRM	40	V	
Reverse Voltage (DC)	VR	40	V	
Forward Current (Average)	lF(AV)	200	mA	
Non Continuous	IFSM	1	۸	
Forward Surge Current <sup>*1</sup>	IFSM	ı	А	
Junction Temperature	Tj	125	°C	
Storage Temperature Range	Tstg	-55 <b>~</b> +150	ွ	

<sup>\*1 :</sup> Non continuous high amplitude 60Hz half-sine wave.

## ■ PACKAGING INFORMATION

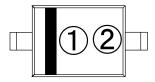




SOD-523

Unit: mm

## ■MARKING RULE



- ①: 1 (Product Number)
- 2: Assembly Lot Number

#### **■PRODUCT NAME**

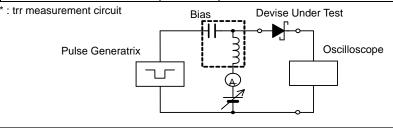
PRODUCT NAME	DEVICE ORIENTATION		
XBS024S15R	SOD-523		
XBS024S15R-G	SOD-523(Halogen & Antimony free)		

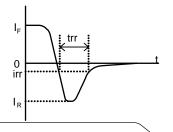
<sup>\*</sup> The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

#### ■ ELECTRICAL CHARACTERISTICS

Ta=25°C

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
	STIVIBUL		MIN.	TYP.	MAX.	UNIT
Forward Voltage	VF1	I <sub>F</sub> =10mA	-	0.33	-	V
	VF2	I <sub>F</sub> =200mA	-	0.53	0.6	V
Reverse Current	lr	V <sub>R</sub> =40V	-	-	2	μΑ
Inter-Terminal Capacity	Ct	V <sub>R</sub> =10V , f=1MHz	-	5	-	pF
Reverse Recovery Time*	trr	I <sub>F</sub> =I <sub>R</sub> =10mA , irr=1mA	-	4	-	ns

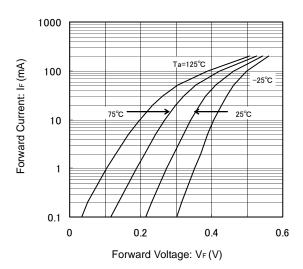




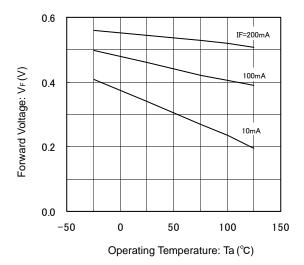
<sup>\*</sup> The device orientation is fixed in its embossed tape pocket.

## ■TYPICAL PERFORMANCE CHARACTERISTICS

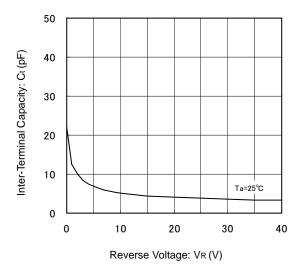
(1) Forward Current vs. Forward Voltage



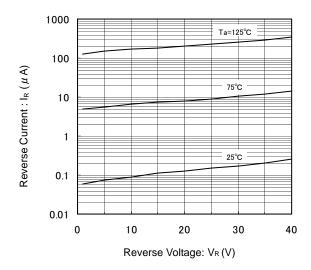
(3) Forward Voltage vs. Operating Temperature



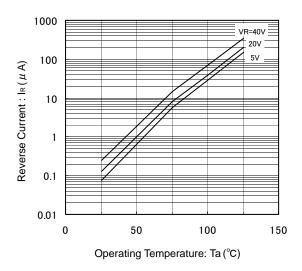
(5) Inter-Terminal Capacity vs. Reverse Voltage



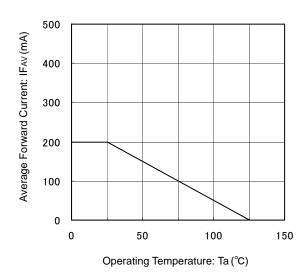
(2) Reverse Current vs. Reverse Voltage



(4) Reverse Current vs. Operating Temperature



(6) Average Forward Current vs. Operating Temperature



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